

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: **Ching-Nan HSIAO, Chao-Sung  
LAI, Yung-Meng HUANG**

Filed: **2/10/2004**

Appl. No.: **10/775,307**

Examiner: **THOMAS, TONIAE M**

Conf. No.: **1517**

Art Unit: **2822**

Title: **MULTI-BIT VERTICAL MEMORY CELL AND METHOD OF FABRIATING  
THE SAME**

Date: **December 21, 2006**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**AMENDMENT**

Sir:

The Office Action mailed on **September 21, 2006** has been carefully considered. In response thereto, the Applicant respectfully requests entry of the amendments and consideration of the remarks as set forth herein below:

**Amendments to the Claims** are reflected in the listing of claims that begins on page 2 of this paper.

**Remarks** begin on page 4 of this paper.

All amendments and remarks made herein are without prejudice.